SCBS015D - NOVEMBER 1988 - REVISED NOVEMBER 1993

- BiCMOS Design Substantially Reduces I_{CCZ}
- Functionally Equivalent to 'ALS29863 and AMD Am29863A
- Power-Up High-Impedance State
- ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015
- Package Options Include Plastic Small-Outline Packages (DW), Ceramic Chip Carriers (FK) and Flatpacks (W), and Standard Plastic and Ceramic 300-mil DIPs (JT, NT)

description

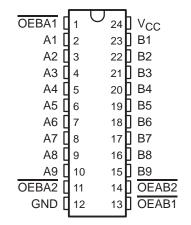
These 9-bit transceivers are designed for asynchronous communication between data buses. The control-function implementation allows for maximum flexibility in timing.

These devices allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending upon the logic levels at the output-enable (OEBA and OEAB) inputs.

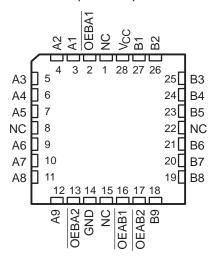
The outputs are in the high-impedance state during power-up and power-down conditions. The outputs remain in the high-impedance state while the device is powered down.

The SN54BCT29863B is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74BCT29863B is characterized for operation from 0°C to 70°C.

SN54BCT29863B ... JT OR W PACKAGE SN74BCT29863B ... DW OR NT PACKAGE (TOP VIEW)



SN54BCT29863B . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

FUNCTION TABLE

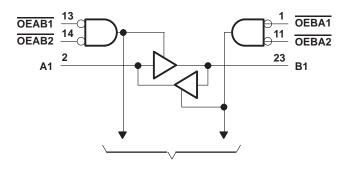
	INP	OPERATION				
OEAB1	OEAB2	OEBA1	OEBA2	OPERATION		
L	L	L	L	Latch A and B		
L	L	Н	Х	A to B		
L	L	Χ	Н	AIOB		
Н	Χ	L	L	B to A		
Х	Н	L	L	B to A		
Н	Χ	Н	Х			
Н	Χ	Χ	Н	Isolation		
Х	Н	Χ	Н	isolation		
Х	Н	Н	Χ			



logic symbol†

OEBA1 11 EN₁ OEBA2 13 OEAB1 EN2 14 OEAB2 23 В1 ⊲ 2 ▽ 22 Α2 **B2** 21 A3 **B3** 5 20 Α4 **B**4 19 Α5 **B5** 18 **B6** A6 17 В7 Α7 16 **B8 A8** 10 15 A9 В9

logic diagram (positive logic)



To Eight Other Channels

Pin numbers shown are for the DW, JT, NT, and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}		0.5 V to 7 V
Input voltage range (I/O ports) (see N	lote 1)	
Input voltage range (excluding I/O po	rts) (see Note 1)	
Voltage range applied to any output i	n the high state	-0.5 V to V_{CC}
Input clamp current		30 mA
Current into any output in the low sta	te: SN54BCT29863B	48 mA
	SN74BCT29863B	96 mA
Operating free-air temperature range	: SN54BCT29863B	–55°C to 125°C
	SN74BCT29863B	0°C to 70°C
Storage temperature range		65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The negative input voltage ratings may be exceeded if the input current rating is observed.



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

recommended operating conditions

		SN54BCT29863B		SN74BCT29863B			UNIT	
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
V _{IL}	Low-level input voltage			0.8			0.8	V
ΙΙΚ	Input clamp current			-18			-18	mA
IOH	High-level output current			-15			-24	mA
lOL	Low-level output current			24			48	mA
TA	Operating free-air temperature	-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54	SN54BCT29863B			SN74BCT29863B			
				MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT	
٧ıK		V _{CC} = 4.5 V,	$I_{I} = -18 \text{ mA}$			-1.2			-1.2	V	
		V _{CC} = 4.5 V	$I_{OH} = -15 \text{ mA}$	2.4	3.3		2.4	3.3			
Vон		vCC = 4.5 v	$I_{OH} = -24 \text{ mA}$				2	3.1		V	
		$V_{CC} = 4.75 V$,	$I_{OH} = -3 \text{ mA}$				2.7				
\/-·	-	V=== 4 E V	I _{OL} = 24 mA		0.35	0.5				V	
VOL		V _{CC} = 4.5 V	$I_{OL} = 48 \text{ mA}$					0.35	0.5	V	
Ц		V _{CC} = 5.5 V,	V _I = 5.5 V			0.1			0.1	mA	
Lee	Control inputs	V 55V	V 07V			20			20		
lН	A or B port‡	$V_{CC} = 5.5 \text{ V},$	$V_{I} = 2.7 \text{ V}$			20			20	μΑ	
1	Control inputs	V 55V	V: 0.5.V			-0.2			-0.2	mA	
IIL	A or B port‡	$V_{CC} = 5.5 \text{ V},$	$V_{I} = 0.5 V$			-0.2			-0.2		
I _{IO(off)}	}	$V_{CC} = 0$,	V _O = 2.7 V			0.1			0.1	mA	
Ios¶		$V_{CC} = 5.5 \text{ V},$	V _O = 0	-75		-250	-75	•	-250	mA	
		V _{CC} = 5.5 V	Outputs high		18	30		18	30		
ICC			Outputs low		30	45		30	45	mA	
			Outputs disabled		6.5	12		6.5	12		
Ci		V _{CC} = 5 V,	V _I = 2.5 V or 0.5 V		6			6		pF	
C _{io}		V _{CC} = 5 V,	V _I = 2.5 V or 0.5 V		8			8		pF	

[†] All typical values are at V_{CC} = 5 V, T_A = 25°C.
‡ For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.
§ I_{O(off)} = Power-off bus-leakage current
¶ Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second.

SN54BCT29863B, SN74BCT29863B 9-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

SCBS015D - NOVEMBER 1988 - REVISED NOVEMBER 1993

switching characteristics (see Note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 5 \text{ V},$ $C_L = 50 \text{ pF},$ $R1 = 500 \Omega,$ $R2 = 500 \Omega,$ $T_A = 25^{\circ}\text{C}$ 'BCT29863B MIN TYP MAX		$C_L = 50 \text{ pF},$ $C_L = 50 \text{ pF},$ $R1 = 500 \Omega,$ $R1 = 500 \Omega,$ $R2 = 500 \Omega,$ $R2 = 500 \Omega,$ $T_A = 25^{\circ}C$ $T_A = MIN \text{ to MAX}^{\dagger}$ $'BCT29863B$ $SN54BCT29863B$ $SN74BCT29863B$					Г29863B МАХ	UNIT	
			IVIIIV	:		MIN	MAX	MIN				
t _{PLH}	A or B	A or B B or A	1	3	4.5	1	5.4	1	5	ns		
tPHL			2	4.8	6.8	2	7.9	2	7.5	110		
^t PZH	OEAB or OEBA	A or B	2	5.1	7	2	9.2	2	8.4	no		
t _{PZL}		AUID	4.5	8.4	10.8	4.5	13.6	4.5	12.6	ns		
t _{PHZ}	OEAB or OEBA	A or B	2	5	7.2	2	9.6	2	8.8	ns		
tPLZ		AUIB	1.7	4.7	6.7	1.7	9.1	1.7	8.1	115		

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

Copyright © 1998, Texas Instruments Incorporated